

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

**TA78M05SB, TA78M06SB, TA78M08SB, TA78M09SB, TA78M10SB
TA78M12SB, TA78M15SB, TA78M18SB, TA78M20SB, TA78M24SB**

0.5 A THREE TERMINAL POSITIVE VOLTAGE REGULATORS

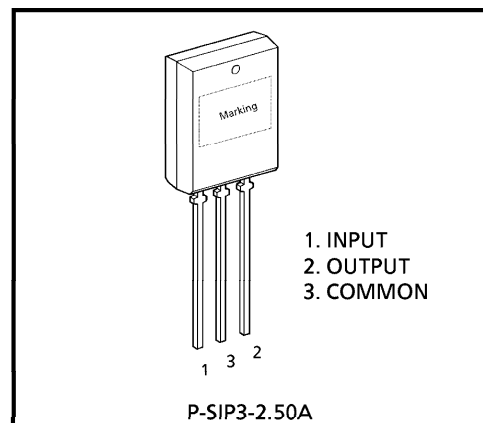
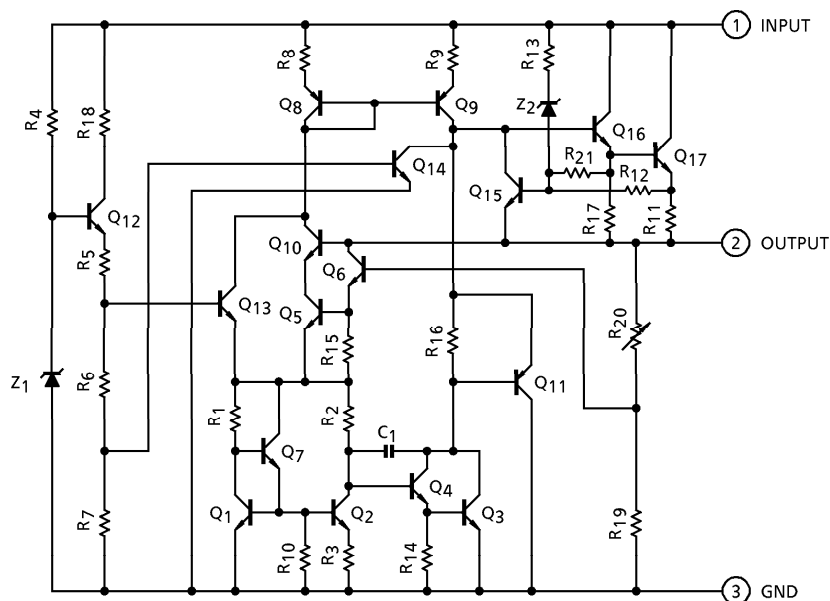
5 V, 6 V, 8 V, 9 V, 10 V, 12 V, 15 V, 18 V, 20 V, 24 V

The TA78M××SB series of fixed-voltage monolithic integrated circuit voltage regulators is designed for a wide range of applications. These regulators employ internal current-limiting, thermal-shutdown and safe-area compensation, making them essentially indestructible. One of these regulators can driver up to 0.5 A of output current.

FEATURES

- Suitable for CMOS, TTL and the other Digital IC's Power Supply.
- Output Current in Excess of 0.5 A
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Package in the Plastic Case TPL ($P_D = 1.8 W$)

EQUIVALENT CIRCUIT



Weight : 1.5 g (Typ.)

980910EBA2

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- The information contained herein is subject to change without notice.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Input Voltage	TA78M05SB	V _{IN}	35	V
	TA78M06SB			
	TA78M08SB			
	TA78M09SB			
	TA78M10SB			
	TA78M12SB		40	
	TA78M15SB			
	TA78M18SB			
	TA78M20SB			
	TA78M24SB			
Power Dissipation	(Ta = 25°C)	P _D	1.8	W
Operating Temperature		T _{opr}	– 30~85	°C
Storage Temperature		T _{stg}	– 55~150	°C
Junction Temperature		T _j	150	°C
Thermal Resistance		R _{th (j-a)}	69.4	°C / W

TA78M05SB

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 10\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	4.8	5.0	5.2	V
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$7\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	4	100
				$8\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	2	
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	25	100
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	$7\text{ V} \leq V_{IN} \leq 20\text{ V}$ $5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	4.75	—	5.25
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.5	8.0	mA
Quiescent Current Change	Line	ΔI_B	$T_j = 25^\circ\text{C}$	$8.5\text{ V} \leq V_{IN} \leq 25.5\text{ V}$, $I_{OUT} = 200\text{ mA}$	—	—	0.8
	Load	ΔI_{BO}		$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	—	0.5
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	50	200	μV_{rms}
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $8\text{ V} \leq V_{IN} \leq 18\text{ V}$, $T_j = 25^\circ\text{C}$	62	69	—	dB
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-0.6	—	$\text{mV}/^\circ\text{C}$

TA78M06SB

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 11\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	5.75	6.0	6.25	V
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$8\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	4	100
				$9\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	2	
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	25	120
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	$8\text{ V} \leq V_{IN} \leq 21\text{ V}$ $5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	5.7	—	6.3
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.5	8.0	mA
Quiescent Current Change	Line	ΔI_B	$T_j = 25^\circ\text{C}$	$9.5\text{ V} \leq V_{IN} \leq 25.5\text{ V}$, $I_{OUT} = 200\text{ mA}$	—	—	0.8
	Load	ΔI_{BO}		$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	—	0.5
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	55	220	μV_{rms}
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $9\text{ V} \leq V_{IN} \leq 19\text{ V}$, $T_j = 25^\circ\text{C}$	59	66	—	dB
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-0.7	—	$\text{mV}/^\circ\text{C}$

TA78M08SB

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 14\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	7.7	8.0	8.3	V
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$10.5\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	5	100
				$11\text{ V} \leq V_{IN} \leq 25\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	3	
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	26	160
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	$10.5\text{ V} \leq V_{IN} \leq 23\text{ V}$ $5\text{ mA} \leq I_{OU} \leq 350\text{ mA}$	7.6	—	8.4
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.6	8.0	mA
Quiescent Current Change	Line	ΔI_B	$T_j = 25^\circ\text{C}$	$11\text{ V} \leq V_{IN} \leq 25.5\text{ V}$, $I_{OUT} = 200\text{ mA}$	—	—	0.8
	Load	ΔI_{BO}		$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	—	0.5
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	60	250	μV_{rms}
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $11.5\text{ V} \leq V_{IN} \leq 21.5\text{ V}$, $T_j = 25^\circ\text{C}$	56	63	—	dB
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-1.0	—	$\text{mV}/^\circ\text{C}$

TA78M09SB

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 15\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	8.64	9.0	9.36	V
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	$11.5\text{ V} \leq V_{IN} \leq 26\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	5	100
				$13\text{ V} \leq V_{IN} \leq 26\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	3	
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	26	180
				$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	$11.5\text{ V} \leq V_{IN} \leq 24\text{ V}$ $5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	8.55	—	9.45
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.6	8.0	mA
Quiescent Current Change	Line	ΔI_B	$T_j = 25^\circ\text{C}$	$12\text{ V} \leq V_{IN} \leq 26.5\text{ V}$, $I_{OUT} = 200\text{ mA}$	—	—	0.8
	Load	ΔI_{BO}		$5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	—	—	0.5
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	60	270	μV_{rms}
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $12.5\text{ V} \leq V_{IN} \leq 22.5\text{ V}$, $T_j = 25^\circ\text{C}$	56	63	—	dB
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-1.1	—	$\text{mV}/^\circ\text{C}$

TA78M12SB

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 19\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	11.5	12.0	12.5	V
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$ $14.5\text{ V} \leq V_{IN} \leq 30\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	7	100	mV
			$16\text{ V} \leq V_{IN} \leq 30\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	3	50	
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$ $5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$	—	27	240	mV
			$5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	120	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$ $14.5\text{ V} \leq V_{IN} \leq 27\text{ V}$ $5\text{ mA} \leq I_{OUT} \leq 350\text{ mA}$	11.4	—	12.6	V
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.8	8.0	mA
Quiescent Current Change	Line	ΔI_B	$T_j = 25^\circ\text{C}$ $15\text{ V} \leq V_{IN} \leq 30.5\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	—	0.8	mA
	Load	ΔI_{BO}		—	—	0.5	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	70	300	μV_{rms}
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $15\text{ V} \leq V_{IN} \leq 25\text{ V}$, $T_j = 25^\circ\text{C}$	55	62	—	dB
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-1.6	—	$\text{mV}/^\circ\text{C}$

TA78M10SB

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 16\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	9.6	10.0	10.4	V
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	—	6	100	mV
			$12.5\text{ V} \leq V_{IN} \leq 26\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	3	50	
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	—	26	200	mV
			$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$ $5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	100	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	9.5	—	10.5	V
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.7	8.0	mA
Quiescent Current Change	Line	1	$T_j = 25^\circ\text{C}$	—	—	0.8	mA
	Load	1	$T_j = 25^\circ\text{C}$	—	—	0.5	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	65	280	μV_{rms}
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $13.5\text{ V} \leq V_{IN} \leq 23.5\text{ V}$, $T_j = 25^\circ\text{C}$	55	62	—	dB
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-1.3	—	$\text{mV}/^\circ\text{C}$

TA78M15SB

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 23\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	14.4	15.0	15.6	V
Line Regulation	Reg·line	1	$T_j = 25^\circ\text{C}$	—	8	100	mV
			$17.5\text{ V} \leq V_{IN} \leq 30\text{ V}$ $I_{OUT} = 200\text{ mA}$	—	4	50	
Load Regulation	Reg·load	1	$T_j = 25^\circ\text{C}$	—	27	300	mV
			$5\text{ mA} \leq I_{OUT} \leq 500\text{ mA}$ $5\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$	—	10	150	
Output Voltage	V_{OUT}	1	$T_j = 25^\circ\text{C}$	14.25	—	15.75	V
Quiescent Current	I_B	1	$T_j = 25^\circ\text{C}$	—	4.8	8.0	mA
Quiescent Current Change	Line	1	$T_j = 25^\circ\text{C}$	—	—	0.8	mA
	Load	1	$T_j = 25^\circ\text{C}$	—	—	0.5	
Output Noise Voltage	V_{NO}	2	$T_a = 25^\circ\text{C}$, $10\text{ Hz} \leq f \leq 100\text{ kHz}$	—	80	450	μV_{rms}
Ripple Rejection	R.R.	3	$f = 120\text{ Hz}$, $I_{OUT} = 100\text{ mA}$ $18.5\text{ V} \leq V_{IN} \leq 28.5\text{ V}$, $T_j = 25^\circ\text{C}$	54	61	—	dB
Short Circuit Current Limit	I_{SC}	1	$T_j = 25^\circ\text{C}$	—	960	—	mA
Dropout Voltage	V_D	1	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Average Temperature Coefficient Of Output Voltage	T_{CVO}	1	$I_{OUT} = 5\text{ mA}$	—	-2.0	—	$\text{mV}/^\circ\text{C}$

TA78M18SB

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 27\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$)

CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Output Voltage		V _{OUT}	1	T _j = 25°C		17.3	18.0	18.7	V
Line Regulation		Reg·line	1	T _j = 25°C	21 V ≤ V _{IN} ≤ 33 V I _{OUT} = 200 mA	—	9	100	mV
					24 V ≤ V _{IN} ≤ 33 V I _{OUT} = 200 mA	—	5	50	
Load Regulation		Reg·load	1	T _j = 25°C	5 mA ≤ I _{OUT} ≤ 500 mA	—	28	360	mV
					5 mA ≤ I _{OUT} ≤ 200 mA	—	10	180	
Output Voltage		V _{OUT}	1	T _j = 25°C	21 V ≤ V _{IN} ≤ 33 V 5 mA ≤ I _{OUT} ≤ 350 mA	17.1	—	18.9	V
Quiescent Current		I _B	1	T _j = 25°C		—	4.8	8.0	mA
Quiescent Current Change	Line	ΔI _B	1	T _j = 25°C	21.5 V ≤ V _{IN} ≤ 33.5 V, I _{OUT} = 200 mA	—	—	0.8	mA
	Load	ΔI _{BO}	1		5 mA ≤ I _{OUT} ≤ 350 mA	—	—	0.5	
Output Noise Voltage		V _{NO}	2	T _a = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	90	490	μV _{rms}
Ripple Rejection		R.R.	3	f = 120 Hz, I _{OUT} = 100 mA 22 V ≤ V _{IN} ≤ 32 V, T _j = 25°C		53	60	—	dB
Short Circuit Current Limit		I _{SC}	1	T _j = 25°C		—	960	—	mA
Dropout Voltage		V _D	1	T _j = 25°C		—	1.7	—	V
Average Temperature Coefficient Of Output Voltage		T _{CV0}	1	I _{OUT} = 5 mA		—	−2.5	—	mV / °C

TA78M20SB

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $V_{IN} = 29\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$)

CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Output Voltage		V _{OUT}	1	T _j = 25°C		19.2	20.0	20.8	V
Line Regulation		Reg·line	1	T _j = 25°C	23 V ≤ V _{IN} ≤ 35 V I _{OUT} = 200 mA	—	10	100	mV
					24 V ≤ V _{IN} ≤ 35 V I _{OUT} = 200 mA	—	6	50	
Load Regulation		Reg·load	1	T _j = 25°C	5 mA ≤ I _{OUT} ≤ 500 mA	—	28	400	mV
					5 mA ≤ I _{OUT} ≤ 200 mA	—	10	200	
Output Voltage		V _{OUT}	1	T _j = 25°C	23 V ≤ V _{IN} ≤ 35 V 5 mA ≤ I _{OUT} ≤ 350 mA	19.0	—	21.0	V
Quiescent Current		I _B	1	T _j = 25°C		—	4.9	8.0	mA
Quiescent Current Change	Line	ΔI _B	1	T _j = 25°C	23.5 V ≤ V _{IN} ≤ 35.5 V, I _{OUT} = 200 mA	—	—	0.8	mA
	Load	ΔI _{BO}	1		5 mA ≤ I _{OUT} ≤ 350 mA	—	—	0.5	
Output Noise Voltage		V _{NO}	2	T _a = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	95	540	μV _{rms}
Ripple Rejection		R.R.	3	f = 120 Hz, I _{OUT} = 100 mA 24 V ≤ V _{IN} ≤ 34 V, T _j = 25°C		53	60	—	dB
Short Circuit Current Limit		I _{SC}	1	T _j = 25°C		—	960	—	mA
Dropout Voltage		V _D	1	T _j = 25°C		—	1.7	—	V
Average Temperature Coefficient Of Output Voltage		T _{CVO}	1	I _{OUT} = 5 mA		—	−3.0	—	mV / °C

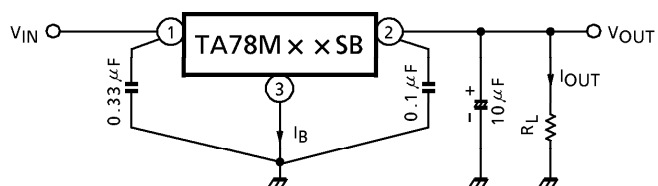
TA78M24SB

ELECTRICAL CHARACTERISTICS

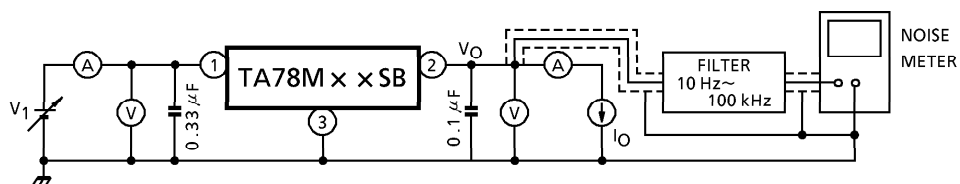
(Unless otherwise specified, $V_{IN} = 33\text{ V}$, $I_{OUT} = 350\text{ mA}$, $0^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $C_{IN} = 0.33\text{ }\mu\text{F}$, $C_{OUT} = 0.1\text{ }\mu\text{F}$)

CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Output Voltage		V _{OUT}	1	T _j = 25°C		23.0	24.0	25.0	V
Line Regulation		Reg·line	1	T _j = 25°C	27 V ≤ V _{IN} ≤ 38 V I _{OUT} = 200 mA	—	12	100	mV
					28 V ≤ V _{IN} ≤ 38 V I _{OUT} = 200 mA	—	7	50	
Load Regulation		Reg·load	1	T _j = 25°C	5 mA ≤ I _{OUT} ≤ 500 mA	—	30	480	mV
					5 mA ≤ I _{OUT} ≤ 200 mA	—	10	240	
Output Voltage		V _{OUT}	1	T _j = 25°C	27 V ≤ V _{IN} ≤ 38 V 5 mA ≤ I _{OUT} ≤ 350 mA	22.8	—	25.2	V
Quiescent Current		I _B	1	T _j = 25°C		—	5.0	8.0	mA
Quiescent Current Change	Line	ΔI _B	1	T _j = 25°C	27.5 V ≤ V _{IN} ≤ 38.5 V, I _{OUT} = 200 mA	—	—	0.8	mA
	Load	ΔI _{BO}	1		5 mA ≤ I _{OUT} ≤ 350 mA	—	—	0.5	
Output Noise Voltage		V _{NO}	2	T _a = 25°C, 10 Hz ≤ f ≤ 100 kHz		—	115	650	μV _{rms}
Ripple Rejection		R.R.	3	f = 120 Hz, I _{OUT} = 100 mA 28 V ≤ V _{IN} ≤ 38 V, T _j = 25°C		50	57	—	dB
Short Circuit Current Limit		I _{SC}	1	T _j = 25°C		—	960	—	mA
Dropout Voltage		V _D	1	T _j = 25°C		—	1.7	—	V
Average Temperature Coefficient Of Output Voltage		T _{CVO}	1	I _{OUT} = 5 mA		—	−3.5	—	mV / °C

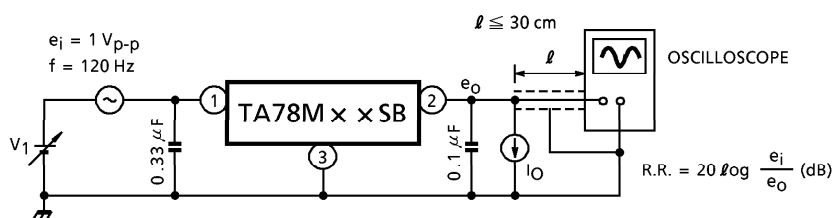
TEST CIRCUIT 1 / STANDARD APPLICATION

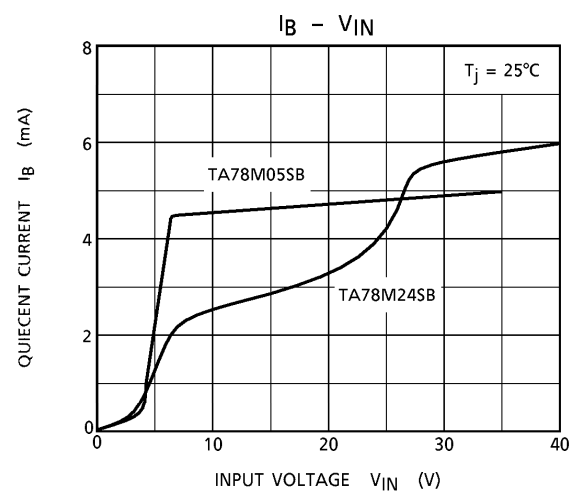
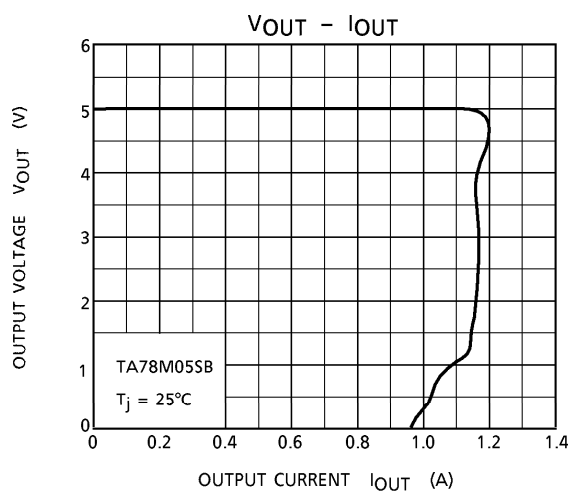
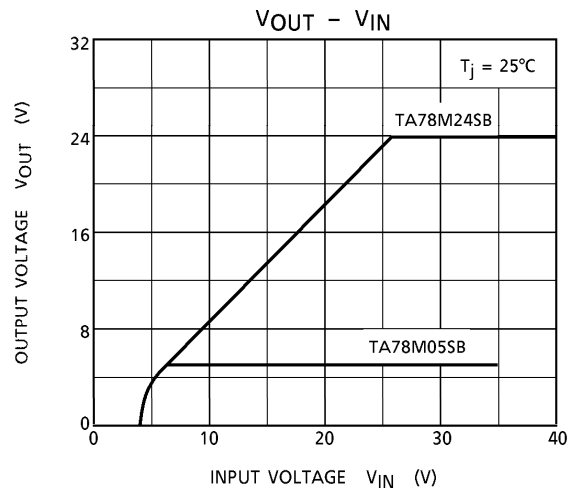
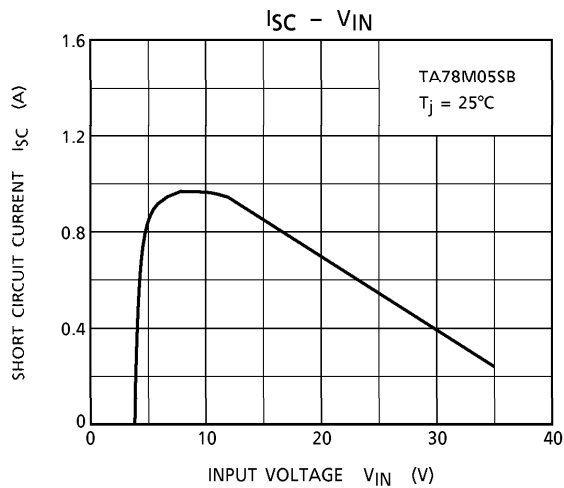
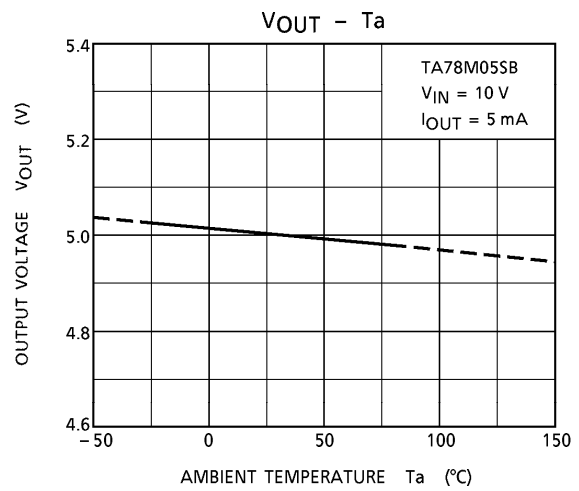
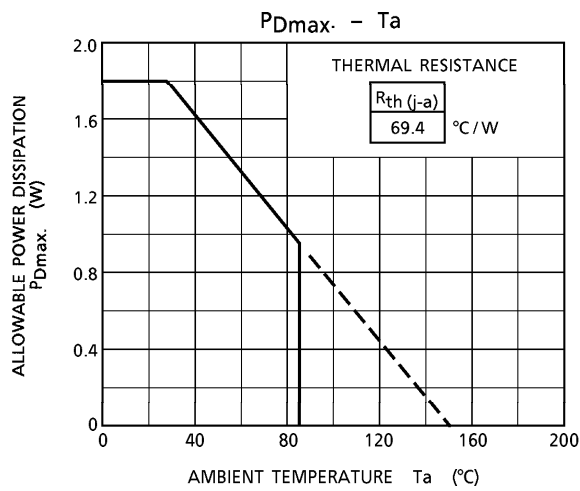


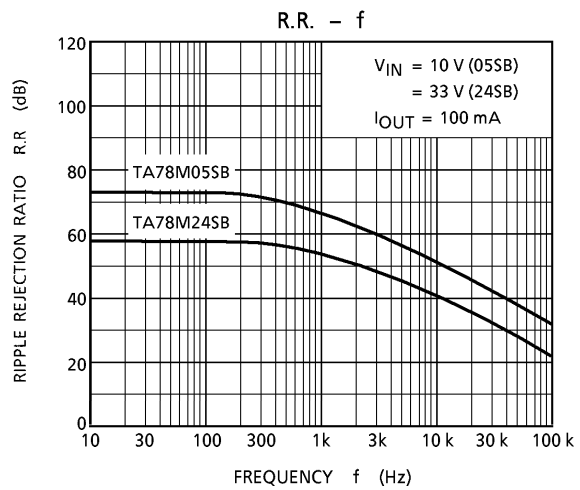
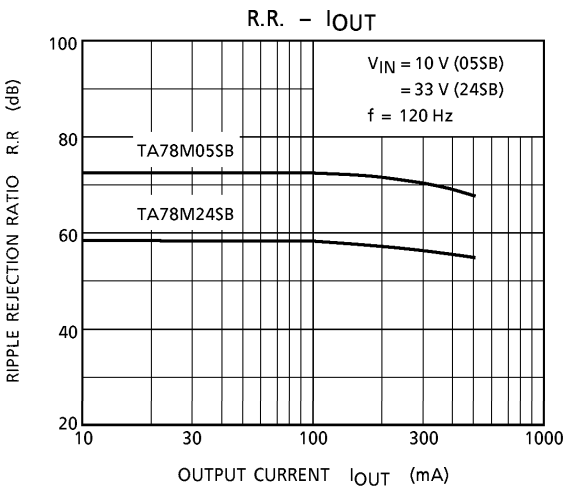
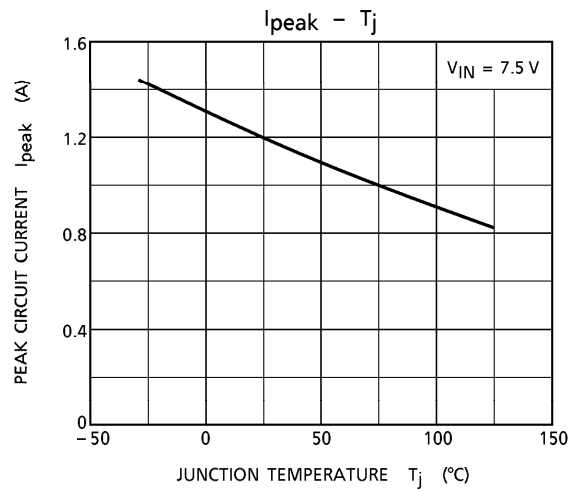
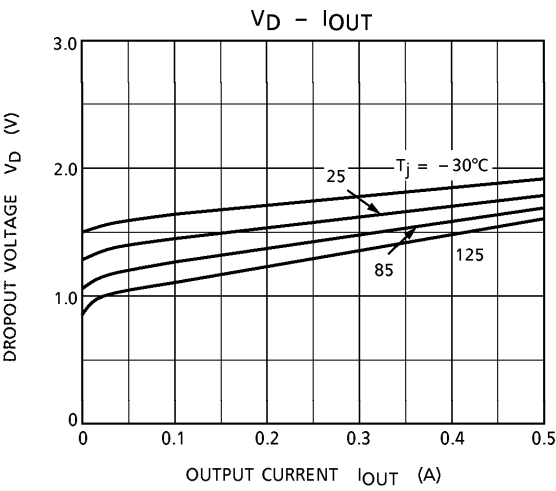
TEST CIRCUIT 2 V_{NO}



TEST CIRCUIT 3 R.R.







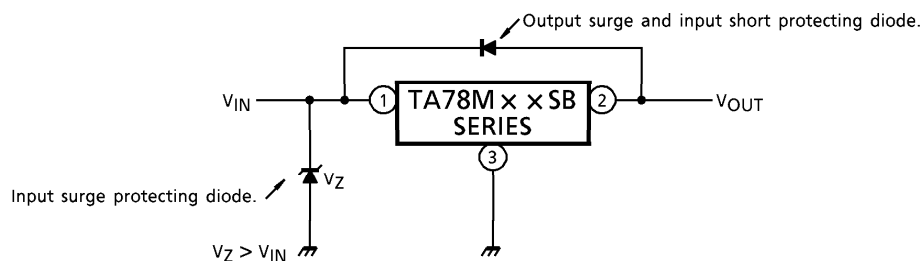
PRECAUTIONS ON APPLICATION

- (1) In regard to GND, be careful not to apply a negative voltage to the input/output terminal. Further, special care is necessary in case of a voltage boost application.
- (2) When a surge voltage exceeding maximum rating is applied to the input terminal or when a voltage in excess of the input terminal voltage is applied to the output terminal, the circuit may be destroyed.

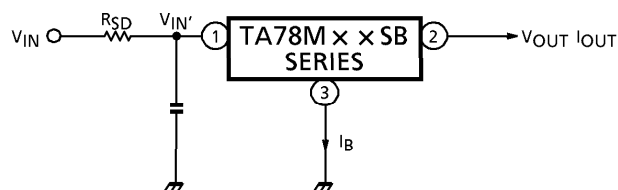
Specially, in the latter case, great care is necessary.

Further, if the input terminal sorts to GND in a state of normal operation, the output terminal voltage becomes higher than the input voltage (GND potential), and the electric charge of a chemical capacitor connected to the output terminal flows into the input side, which may cause the destruction of circuit.

In these cases, take such steps as a zener diode and a general silicon diode are connected to the circuit, as shown in the following figure.



- (3) When the input voltage is too high, the power dissipation of three terminal regulator increases because of series regulator, so that the junction temperature rises. In such a case, it is recommended to reduce the power dissipation by inserting the power limiting resistor R_{SD} in the input terminal, and to reduce the junction temperature as a result.



The power dissipation P_D of IC is expressed in the following equation.

$$P_D = (V_{IN'} - V_{OUT}) \cdot I_{OUT} + V_{IN'} \cdot I_B$$

If $V_{IN'}$ is reduced below the lowest voltage necessary for the IC, the parasitic oscillation will be caused according to circumstances.

In determining the resistance value of R_{SD} , design with margin should be made by making reference to the following equation.

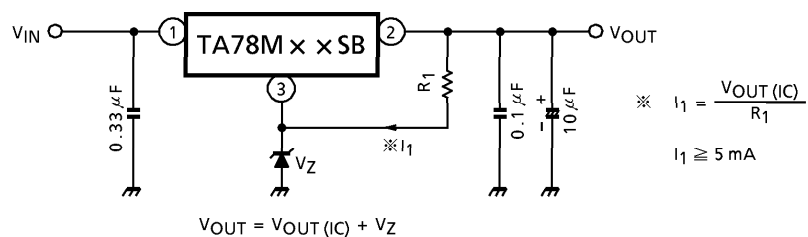
$$R_{SD} < \frac{V_{IN} - V_{IN'}}{I_{OUT} + I_B}$$

- (4) Connect the input terminal and GND, and the output terminal and GND, by capacitor respectively. The capacitances should be determined experimentally because they depend on prented patterns. In particular, adequate investigation should be made so that there is no problem even at time of high or low temperature.

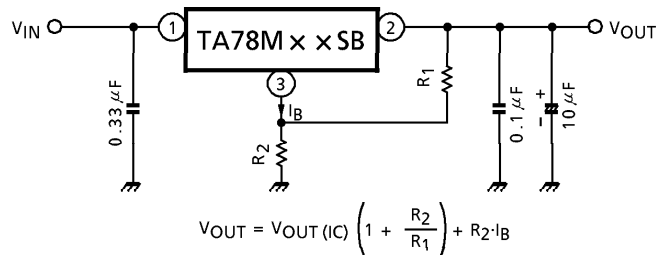
APPLICATION CIRCUITS

(1) VOLTAGE BOOST REGULATOR

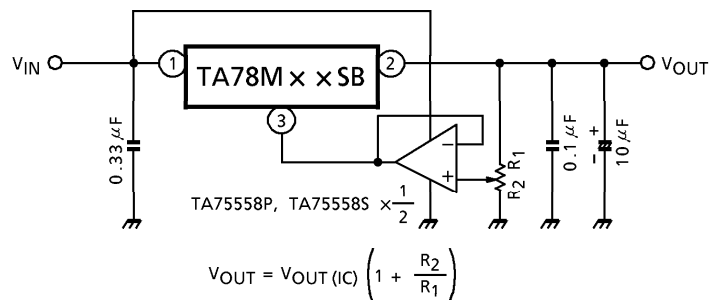
(a) Voltage boost by use of zener diode



(b) Voltage boost by use of resistor

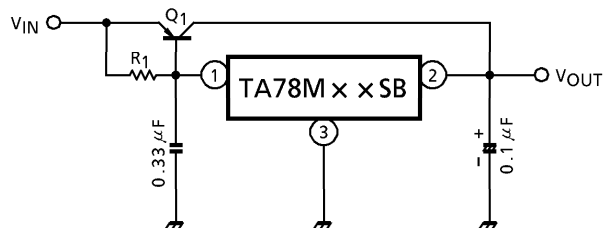


(c) Adjustable output regulator



(2) CURRENT BOOST REGULATOR

(a) CURRENT BOOST VOLTAGE REGULATOR



Heat sink is needed for Q₁

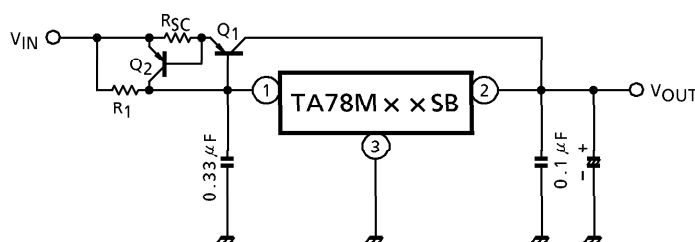
$$R_1 \cong \frac{V_{BE1}}{I_B \text{ MAX}}$$

where,

V_{BE1} : V_{BE} of external transistor Q₁.

$I_B \text{ MAX}$: Quiescent current of IC.

(b) SHORT-CIRCUIT PROTECTION

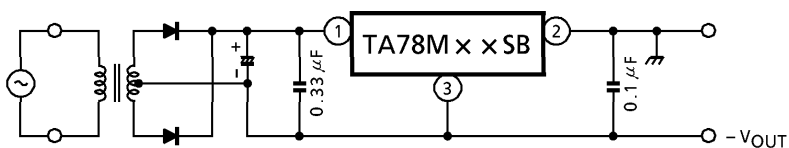


$$R_{SC} = \frac{V_{BE2}}{I_{SC}}$$

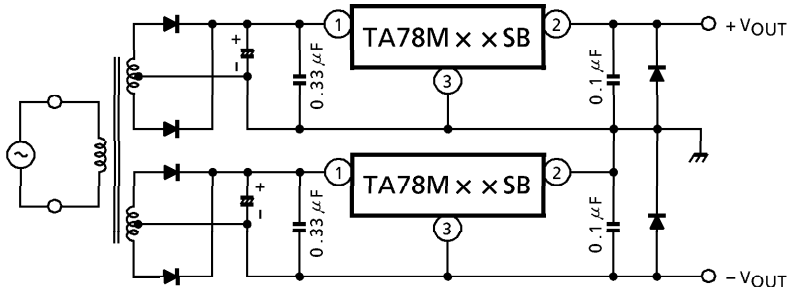
where,

I_{SC} : Short-circuit current

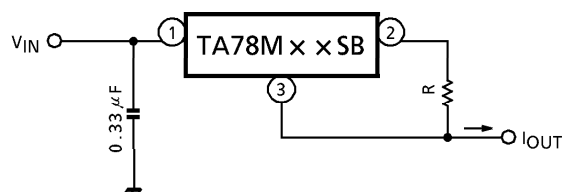
(3) NEGATIVE REGULATOR



(4) POSITIVE AND NEGATIVE REGULATOR



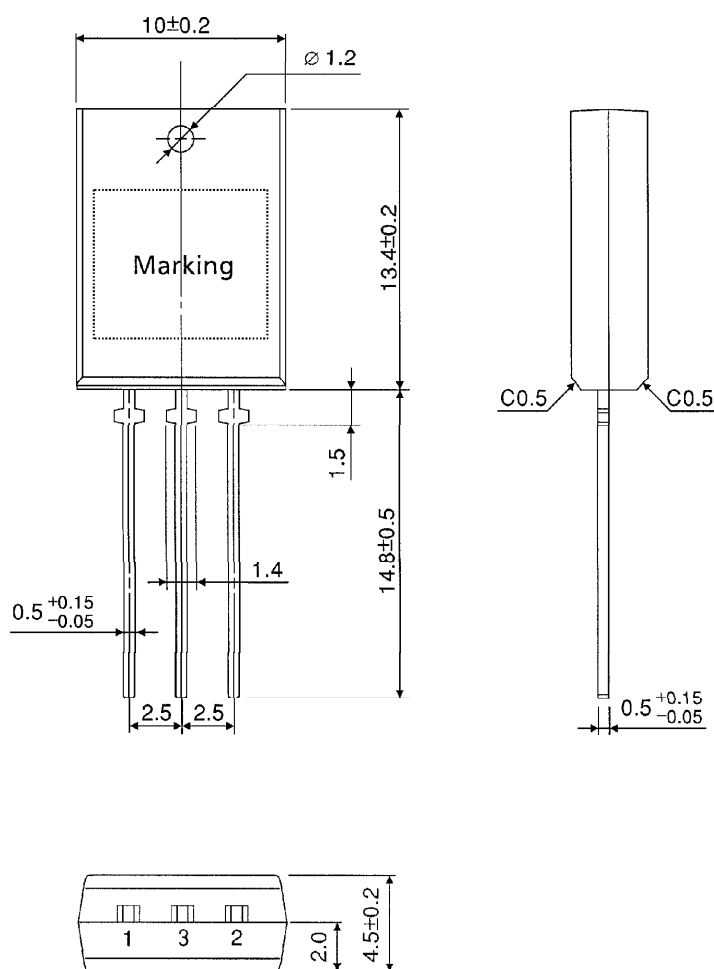
(5) CURRENT REGULATOR



$$I_{OUT} = \frac{V_{OUT}}{R} + I_B$$

PACKAGE DIMENSIONS P-SIP3-2.50A

Unit : mm



Weight : 1.5 g (Typ.)